

# 11.3 Gbps Limiting Transimpedance Amplifier With RSSI

Check for Samples: ONET8541T

### **FEATURES**

- 9 GHz Bandwidth
- 4 kΩ Differential Small Signal Transimpedance
- -20dBm Sensitivity
- 0.95 µA<sub>RMS</sub> Input Referred Noise
- 2.5 mA<sub>PP</sub> Input Overload Current
- · Received Signal Strength Indication (RSSI)
- · 90 mW Typical Power Dissipation
- CML Data Outputs with On-Chip 50 $\Omega$  Back-Termination
- On Chip Supply Filter Capacitor

### Single 3.3 V Supply

• Die Size: 870 μm × 1036 μm

### **APPLICATIONS**

- 10G Ethernet
- 8G and 10G Fibre Channel
- 10G EPON
- SONET OC-192
- 6G CPRI and OBSAI
- PIN Preamplifier Receivers

### **DESCRIPTION**

The ONET8541T is a high-speed, high gain, limiting transimpedance amplifier used in optical receivers with data rates up to 11.3Gbps. It features low input referred noise, 9GHz bandwidth,  $4k\Omega$  small signal transimpedance, and a received signal strength indicator (RSSI).

The ONET8541T is available in die form, includes an on-chip  $V_{CC}$  bypass capacitor and is optimized for packaging in a TO can.

The ONET8541T requires a single 3.3V ±10% supply and its power efficient design typically dissipates less than 90mW. The device is characterized for operation from –40°C to 100°C case (IC back side) temperature.







This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### **BLOCK DIAGRAM**

A simplified block diagram of the ONET8541T is shown in Figure 1.

The ONET8541T consists of the signal path, supply filters, a control block for dc input bias, automatic gain control (AGC) and received signal strength indication (RSSI). The RSSI provides the bias for the TIA stage and the control for the AGC.

The signal path consists of a transimpedance amplifier stage, a voltage amplifier, and a CML output buffer. The on-chip filter circuit provides a filtered  $V_{CC}$  for the PIN photodiode and for the transimpedance amplifier.

The dc input bias circuit and automatic gain control use internal low pass filters to cancel the dc current on the input and to adjust the transimpedance amplifier gain. Furthermore, circuitry is provided to monitor the received signal strength.

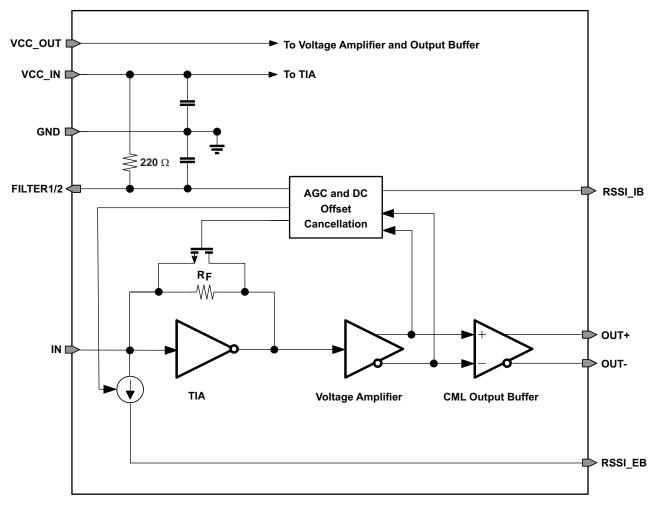


Figure 1. Simplified Block Diagram of the ONET8541T



### **BOND PAD ASSIGNMENT**

The ONET8541T is available in die form. The locations of the bondpads are shown in Figure 2.

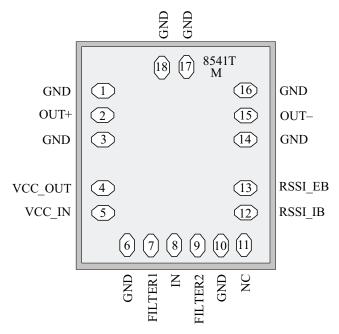


Figure 2. Bond Pad Assignment of ONET8541T

### **PIN FUNCTIONS**

P	IN	TVDE	DESCRIPTION
NAME	NO.	TYPE	DESCRIPTION
GND	1, 3, 6, 10 14, 16 – 18	Supply	Circuit ground. All GND pads are connected on die. Bonding all pads is optional; however, for optimum performance a good ground connection is mandatory.
OUT+	2	Analog output	Non-inverted CML data output. On-chip $50\Omega$ back-terminated to $V_{CC}$ .
VCC_OUT	4	Supply	2.97V–3.63V supply voltage for the voltage and CML amplifiers.
VCC_IN	5	Supply	2.97V–3.63V supply voltage for input TIA stage.
FILTER	7, 9	Analog	Bias voltage for photodiode cathode. These pads are internally connected to an $220\Omega$ resistor to $V_{CC}$ and a filter capacitor to ground (GND).
IN	8	Analog input	Data input to TIA (photodiode anode).
NC	11	No Connect	Do not connect
RSSI_IB	12	Analog output	Analog output current proportional to the input data amplitude. Indicates the strength of the received signal (RSSI) if the photo diode is biased from the TIA. Connected to an external resistor to ground (GND). For proper operation, ensure that the voltage at the RSSI pad does not exceed $V_{CC} = 0.65V$ . If the RSSI feature is not used this pad should be left open.
RSSI_EB	13	Analog output	Optional use when operated with external PD bias (e.g. APD). Analog output current proportional to the input data amplitude. Indicates the strength of the received signal (RSSI). Connected to an external resistor to ground (GND). For proper operation, ensure that the voltage at the RSSI pad does not exceed $V_{\rm CC}$ – 0.65V. If the RSSI feature is not used this pad should be left open.
OUT-	15	Analog output	Inverted CML data output. On-chip $50\Omega$ back-terminated to $V_{\text{CC}}$ .



### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V <sub>CC_IN</sub> , V <sub>CC_OUT</sub>	Supply voltage (2)	-0.3	4.0	V
V <sub>FILTER1</sub> , V <sub>FILTER2</sub> , V <sub>OUT+</sub> , V <sub>OUT-</sub> , V <sub>RSSI_IB</sub> , V <sub>RSSI_EB</sub>	Voltage at FILTER1, FILTER2, OUT+, OUT-, RSSI_IB, RSSI_EB <sup>(2)</sup>	-0.3	4.0	V
I <sub>IN</sub>	Current into IN	-0.7	3.5	mA
I <sub>FILTER</sub>	Current into FILTER1, FILTER2	-8	8	mA
I <sub>OUT+</sub> , I <sub>OUT-</sub>	Continuous current at outputs	-8	8	mA
ECD	ESD rating at all pins except input IN	2		kV (HBM)
ESD	ESD rating at input IN	0.5		kV(HBM)
T <sub>J,max</sub>	Maximum junction temperature		125	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### RECOMMENDED OPERATING CONDITIONS

	PARAMETER	CONDITIONS	MIN	NOM	MAX	UNIT
$V_{CC}$	Supply voltage		2.97	3.3	3.63	V
$T_A$	Operating backside die temperature		-40		100 <sup>(1)</sup>	°C
L <sub>FILTER</sub> , L <sub>IN</sub>	Wire-bond inductor at pins FILTER and IN			0.3	0.5	nΗ
C <sub>PD</sub>	Photodiode capacitance			0.2		pF

<sup>(1) 105°</sup>C maximum junction temperature

## DC ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted). Typical values are at  $V_{CC} = 3.3 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{CC}$	Supply voltage		2.97	3.3	3.63	V
I <sub>VCC</sub>	Cumply augrant	Input current i <sub>IN</sub> < 1000 μA <sub>PP</sub>		27	40 <sup>(1)</sup>	A
	Supply current	Input current i <sub>IN</sub> < 2500 μA <sub>PP</sub>			45 <sup>(1)</sup>	mA
V <sub>IN</sub>	Input bias voltage		0.75	0.85	0.98	V
R <sub>OUT</sub>	Output resistance	Single-ended to V <sub>CC</sub>	40	50	60	Ω
R <sub>FILTER</sub>	Photodiode filter resistance			220		Ω

(1) Including RSSI current

<sup>(2)</sup> All voltage values are with respect to network ground terminal.



### **AC ELECTRICAL CHARACTERISTICS**

over recommended operating conditions (unless otherwise noted). Typical values are at  $V_{CC} = +3.3$  V and  $T_A = 25$ °C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Z <sub>21</sub>	Small signal transimpedance	Differential output; Input current $i_{IN} = 20 \mu A_{PP}$	2500	4000		Ω
f <sub>HSS,3dB</sub>	Small signal bandwidth	$i_{IN} = 16 \mu A_{PP}$ (1)	7	9		GHz
f <sub>L,3dB</sub>	Low frequency –3 dB bandwidth	16 μA < i <sub>IN</sub> < 2000 μA <sub>PP</sub>		30	100	kHz
i <sub>N,IN</sub>	Input referred RMS noise	10 GHz bandwidth (2)		0.95	1.4	μΑ
S <sub>US</sub>	Unstressed sensitivity	10.3125 Gbps, PRBS31 pattern, 1310 nm, BER 10 <sup>-12</sup>		-20		dBm
DJ	Deterministic jitter	25 μA <sub>PP</sub> < i <sub>IN</sub> < 500 μA <sub>PP</sub> (10.3125 Gbps, K28.5 pattern)		6	12	
		$500 \mu A_{PP} < i_{IN} < 2000 \mu A_{PP}$ (10.3125 Gbps, K28.5 pattern)		6	14	ps <sub>PP</sub>
DJ <sub>OL</sub>	Overload deterministic jitter	2000 μ $A_{PP}$ < $i_{IN}$ < 2500 μ $A_{PP}$ (10.3125 Gbps, K28.5 pattern)		7	16	ps <sub>PP</sub>
$V_{OUT,D,MAX}$	Maximum differential output voltage	Input current i <sub>IN</sub> = 500 μA <sub>PP</sub>	180	300	420	$mV_{PP}$
A <sub>RSSI_IB</sub>	RSSI gain internal bias	Resistive load to GND <sup>(3)</sup>	0.48	0.5	0.52	A/A
	RSSI internal bias output offset current (no light) (4)		2	7	16	μA
A <sub>RSSI_EB</sub>	RSSI gain external bias	Resistive load to GND <sup>(3)</sup>	0.43		0.6	A/A
	RSSI external bias output offset current (no light)			25		μA
PSNR	Power supply noise rejection	F < 10 MHz <sup>(5)</sup> , Supply filtering according to SFF8431		<b>–15</b>		dB

<sup>(1)</sup> The small signal bandwidth is specified over process corners, temperature, and supply voltage variation. The assumed photodiode capacitance is 0.2 pF and the bond-wire inductance is 0.3 nH. The small signal bandwidth strongly depends on environmental parasitics. Careful attention to layout parasitics and external components is necessary to achieve optimal performance.

(2) Input referred RMS noise is (RMS output noise)/ (gain at 100 MHz).

<sup>(3)</sup> The RSSI output is a current output, which requires a resistive load to ground (GND). The voltage gain can be adjusted for the intended application by choosing the external resistor; however, for proper operation, ensure that the voltage at RSSI does not exceed V<sub>CC</sub> – 0.65V.

<sup>(4)</sup> Offset is added to improve accuracy below 5μA. When measured without input current (no light) the offset can be subtracted as a constant offset from RSSI measurements.

<sup>(5)</sup> PSNR is the differential output amplitude divided by the voltage ripple on supply; no input current at IN.



#### **DETAILED DESCRIPTION**

### **SIGNAL PATH**

The first stage of the signal path is a transimpedance amplifier which converts the photodiode current into a voltage. If the input signal current exceeds a certain value, the transimpedance gain is reduced by means of a nonlinear AGC circuit to limit the signal amplitude.

The second stage is a limiting voltage amplifier that provides additional limiting gain and converts the single ended input voltage into a differential data signal. The output stage provides CML outputs with an on-chip  $50\Omega$  back-termination to  $V_{CC}$ .

### **FILTER CIRCUITRY**

The FILTER pins provide a filtered  $V_{CC}$  for a PIN photodiode bias. The on-chip low pass filter for the photodiode is implemented using a filter resistor of  $220\Omega$  and a capacitor. The corresponding corner frequency is below 5MHz. The supply voltages for the transimpedance amplifier are filtered by means of on-chip capacitors, thus avoiding the necessity to use an external supply filter capacitor. The input stage has a separate  $V_{CC}$  supply (VCC\_IN) which is not connected on chip to the supply of the limiting and CML stages (VCC\_OUT).

#### **AGC AND RSSI**

The voltage drop across the internal photodiode supply-filter resistor is monitored by the bias and RSSI control circuit block in the case where a PIN diode is biased using the FILTER pins.

If the dc input current exceeds a certain level then it is partially cancelled by means of a controlled current source. This keeps the transimpedance amplifier stage within sufficient operating limits for optimum performance.

The automatic gain control circuitry adjusts the voltage gain of the AGC amplifier to ensure limiting behavior of the complete amplifier.

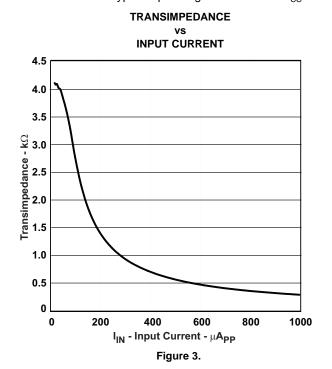
Finally this circuit block senses the current through the filter resistor and generates a mirrored current that is proportional to the input signal strength. The mirrored current is available at the RSSI\_IB output and can be sunk to ground (GND) using an external resistor. For proper operation, ensure that the voltage at the RSSI\_IB pad does not exceed  $V_{\rm CC} = 0.65V$ .

If an APD or PIN photodiode is used with an external bias then the RSSI\_EB pin should be used. However, for greater accuracy under external photo diode biasing conditions, it is recommended to derive the RSSI from the external bias circuitry.



### TYPICAL OPERATION CHARACTERISTICS

Typical operating condition is at  $V_{CC} = 3.3 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$  (unless otherwise noted)



# SMALL SIGNAL TRANSIMPENDANCE **AMBIENT TEMPERATURE** 8000 7000 6000 Transimpedance - □ 5000 4000 3000 2000 1000 -20 20 40 100 -40 T<sub>A</sub> - Ambient Temperature - °C

# SMALL SIGNAL TRANSFER CHARACTERISTICS

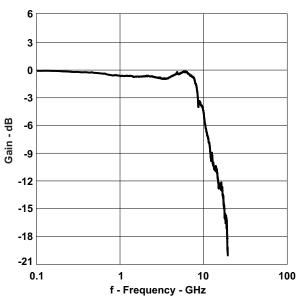


Figure 5.

### SMALL SIGNAL BANDWIDTH

Figure 4.

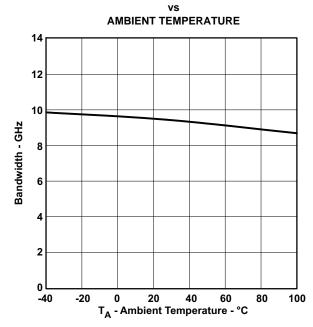
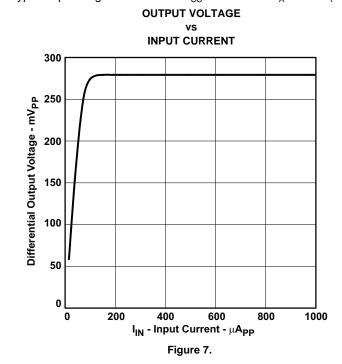


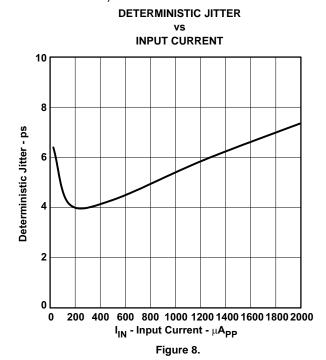
Figure 6.



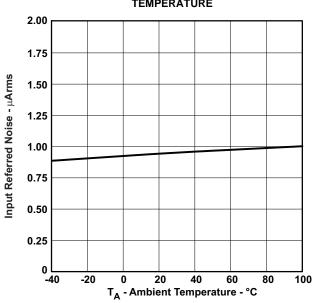
# **TYPICAL OPERATION CHARACTERISTICS (continued)**

Typical operating condition is at  $V_{CC} = 3.3 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$  (unless otherwise noted)





INPUT REFERRED NOISE vs TEMPERATURE



1000 900 800 RSSI\_IB Output Current - µA 700 600 500 400 300 200 100 200 400 600 1000 1200 Average Input Current - µA

Figure 10.

**RSSI\_IB OUTPUT CURRENT** 

**AVERAGE INPUT CURRENT** 

Figure 9.



## **TYPICAL OPERATION CHARACTERISTICS (continued)**

Typical operating condition is at  $V_{CC} = 3.3 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$  (unless otherwise noted)

# OUTPUT EYE-DIAGRAM AT 10.3 GBPS AND 20 $\mu A_{PP}$ INPUT CURRENT

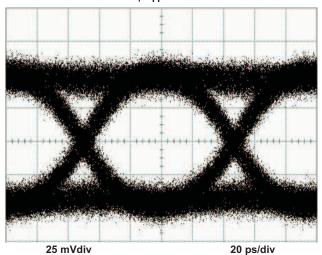


Figure 11.

# OUTPUT EYE-DIAGRAM AT 10.3 GBPS AND 100 $\mu A_{PP}$ INPUT CURRENT

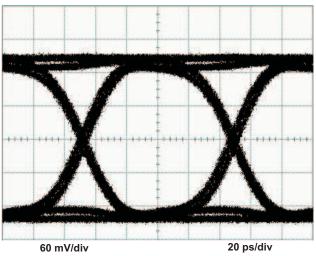


Figure 12.

# OUTPUT EYE-DIAGRAM AT 10.3 GBPS AND 500 $\mu A_{PP}$ INPUT CURRENT

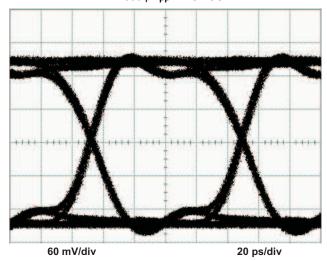


Figure 13.

# OUTPUT EYE-DIAGRAM AT 10.3 GBPS AND 2 mA<sub>PP</sub> INPUT CURRENT

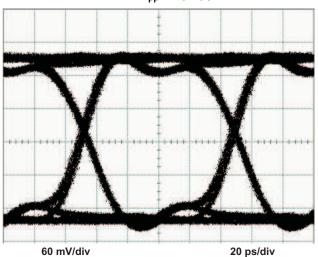


Figure 14.



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#### **APPLICATION INFORMATION**

Figure 15 shows the ONET8541T used in a typical fiber optic receiver using the internal photodiode bias. The ONET8541T converts the electrical current generated by the PIN photodiode into a differential output voltage. The FILTER inputs provide a dc bias voltage for the PIN that is low pass filtered by the combination of an internal  $220\Omega$  resistor and a capacitor. Because the voltage drop across the  $220\Omega$  resistor is sensed and used by the bias circuit, the photodiode must be connected to the FILTER pads for the bias to function correctly.

The RSSI output is used to mirror the photodiode output current and can be connected via a resistor to GND. The voltage gain can be adjusted for the intended application by choosing the external resistor; however, for proper operation of the ONET8541T, ensure that the voltage at RSSI never exceeds  $V_{CC}$  – 0.65V. If the RSSI output is not used while operating with internal PD bias, it should be left open.

The OUT+ and OUT- pins are internally terminated by  $50\Omega$  pull-up resisters to VCC. The outputs must be ac coupled, for example by using  $0.1\mu\text{F}$  capacitors, to the succeeding device.

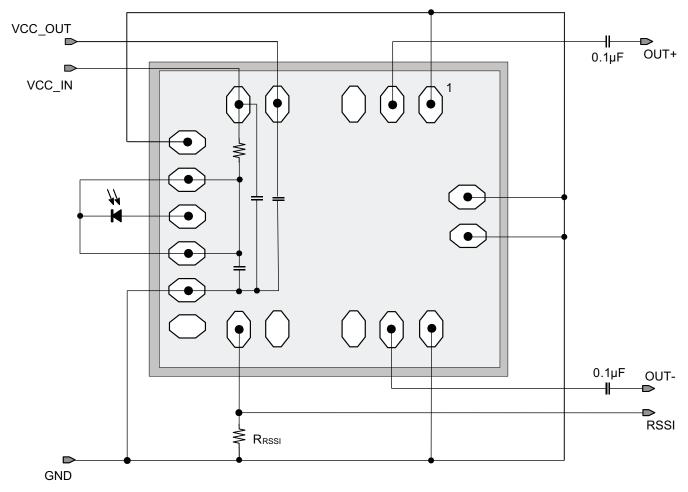


Figure 15. Basic Application Circuit for PIN Receivers

#### **ASSEMBLY RECOMMENDATIONS**

Careful attention to assembly parasitics and external components is necessary to achieve optimal performance.

Recommendations that optimize performance include:

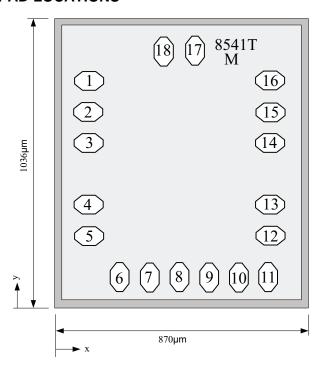
- 1. Minimize the total capacitance on the IN pad by using a low capacitance photodiode and paying attention to stray capacitances. Place the photodiode close to the ONET8541T die in order to minimize the bond wire length and thus the parasitic inductance.
- 2. Use identical termination and symmetrical transmission lines at the ac coupled differential output pins OUT+



and OUT-.

3. Use short bond wire connections for the supply terminals VCC\_IN, VCC\_OUT, and GND. Supply voltage filtering is provided on chip but filtering may be improved by using an additional external capacitor.

## **CHIP DIMENSIONS AND PAD LOCATIONS**



Die Thickness: 203 ± 13  $\mu$ m

Pad Dimensions: 105  $\mu$ m  $\times$  65  $\mu$ m Die Size: 870  $\pm$  40  $\mu$ m  $\times$  1036  $\pm$  40  $\mu$ m

PAD		DINATES ed to pad 1)	SYMBOL TYPE		DESCRIPTION
	<b>x (μm)</b>	<b>y (μm)</b>			
1	0	0	GND	Supply	Circuit ground
2	0	-115	OUT+	Analog output	Non-inverted data output
3	0	-230	GND	Supply	Circuit ground
4	0	-460	VCC_OUT	Supply	3.3V supply voltage
5	0	-575	VCC_IN	Supply	3.3V supply voltage
6	115.5	-728	GND	Supply	Circuit ground
7	225.5	-728	FILTER1	Analog	Bias voltage for photodiode
8	335.5	-728	IN	Analog input	Data input to TIA
9	445.5	-728	FILTER2	Analog	Bias voltage for photodiode
10	555.5	-728	GND	Supply	Circuit ground
11	665.5	-728	NC	No connect	Do not connect
12	671	-575	RSSI_IB	Analog output	RSSI output signal for internally biased receivers
13	671	-460	RSSI_EB	Analog output	RSSI output signal for externally biased receivers
14	671	-230	GND	Supply	Circuit ground
15	671	-115	OUT-	Analog output	Inverted data output
16	671	0	GND	Supply	Circuit ground
17	393	109	GND	Supply	Circuit ground



PAD	COORDINATES PAD (referenced to pad 1)		SYMBOL	TYPE	DESCRIPTION
	<b>x (µm)</b>	<b>y (μm)</b>			
18	278	109	GND	Supply	Circuit ground

### **TO46 LAYOUT EXAMPLE**

An example for a layout using a ground-signal-ground (GSG) type pin photodiode in a 5 pin TO46 can is shown in Figure 16. Figure 17 shows an example with a PIN photodiode having two contacts on the topside.

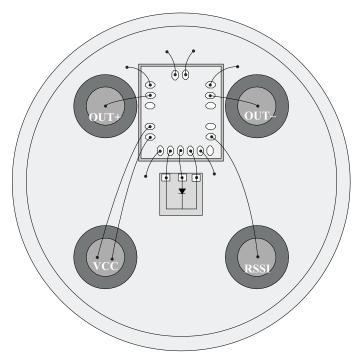


Figure 16. TO46 5 Pin Layout Using the ONET8541T with a GSG PIN Diode



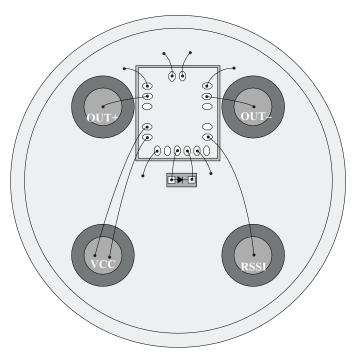


Figure 17. TO46 5 Pin Layout Using the ONET8541T with a Two Contact PIN Diode

### SLLSE85A -JULY 2011-REVISED AUGUST 2011



# **REVISION HISTORY**

CI	hanges from Origir	al (July 2011) to Revision A	Page
•	Changed die size		
•	Changed die size		

11-Nov-2025 www.ti.com

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
ONET8541TY	Active	Production	DIESALE (Y)   0	360   BULK	-	Call TI	Call TI	-40 to 100	
ONET8541TY.A	Active	Production	DIESALE (Y)   0	360   BULK	-	Call TI	Call TI	-40 to 100	
ONET8541TYS4	Active	Production	WAFERSALE (YS)   0	1   OTHER	-	Call TI	Call TI	-40 to 100	
ONET8541TYS4.A	Active	Production	WAFERSALE (YS)   0	1   OTHER	-	Call TI	Call TI	-40 to 100	

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

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